# 74HC257; 74HCT257

# Quad 2-input multiplexer; 3-state Rev. 05 — 13 January 2010

Product data sheet

#### **General description** 1.

The 74HC257; 74HCT257 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL).

The 74HC257 and 74HCT257 have four identical 2-input multiplexers with 3-state outputs, which select 4 bits of data from two sources and are controlled by a common data select input (S).

The data inputs from source 0 (110 to 410) are selected when input S is LOW and the data inputs from source 1 (111 to 411) are selected when S is HIGH. Data appears at the outputs (1Y to 4Y) in true (non-inverting) form from the selected inputs.

The 74HC257 and 74HCT257 are the logic implementation of a 4-pole, 2-position switch, where the position of the switch is determined by the logic levels applied to S. The outputs are forced to a high-impedance OFF-state when  $\overline{OE}$  is HIGH.

The logic equations for the outputs are:

$$1\overline{Y} = \overline{OE} \bullet (111 \bullet S \bullet 110 \bullet \overline{S})$$

$$2\overline{Y} = \overline{OE} \bullet (2I1 \bullet S \bullet 2I0 \bullet \overline{S})$$

$$3\overline{Y} = \overline{OE} \bullet (3I1 \bullet S \bullet 3I0 \bullet \overline{S})$$

$$4\overline{Y} = \overline{OE} \bullet (4I1 \bullet S \bullet 4I0 \bullet \overline{S})$$

Except for their non-inverting (true) outputs the 74HC257; 74HCT257 are identical to the 74HC258.

#### **Features** 2.

- Non-inverting data path
- 3-state outputs interface directly with system bus
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ♦ HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



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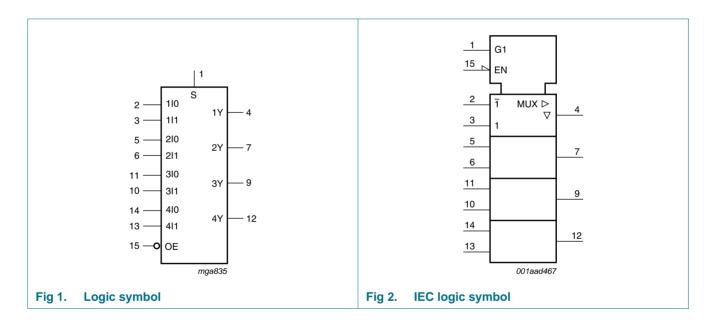
#### **Ordering information** 3.

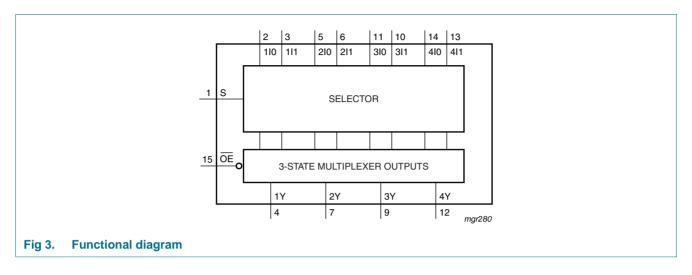
**Ordering information** Table 1.

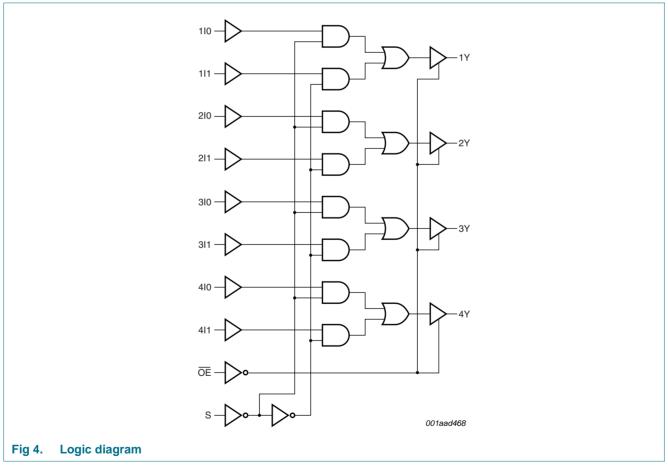
Type number	Package				
	Temperature range	Name	Description	Version	
74HC257N	-40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4	
74HCT257N					
74HC257D	−40 °C to +125 °C	°C to +125 °C SO16 plastic small outline package; 16 leads; body wid	plastic small outline package; 16 leads; body width 3.9 mm	mm SOT109-1	
74HCT257D					
74HC257DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1	
74HCT257DB			body width 5.3 mm		
74HC257PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1	
74HCT257PW			body width 4.4 mm		

## **Functional diagram**

**Product data sheet** 

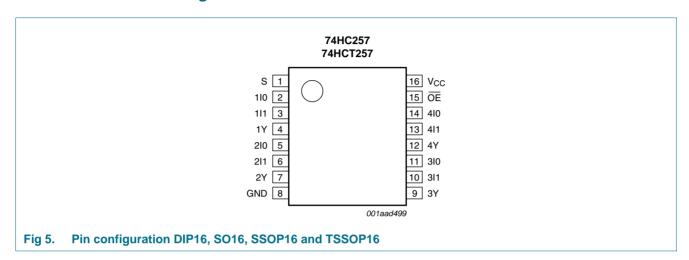






## 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
S	1	common data select input
110 to 410	2, 5, 11, 14	data input from source 0
111 to 411	3, 6, 10, 13	data input from source 1
1Y to 4Y	4, 7, 9, 12	3-state multiplexer output
GND	8	ground (0 V)
ŌĒ	15	3-state output enable input (active LOW)
$V_{CC}$	16	supply voltage

## 6. Functional description

#### 6.1 Function table

Table 3. Function table[1]

		Input	Output	
OE	S	nl0	nl1	nY
Н	X	X	X	Z
L	Н	Χ	L	L
L	Н	Χ	Н	Н
L	L	L	X	L
L	L	Н	X	Н

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		0, 1		.0	,
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or} $ $V_I > V_{CC} + 0.5 \text{ V} $	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or} $ $V_O > V_{CC} + 0.5 \text{ V} $	-	±20	mA
lo	output current	$V_O = -0.5 \text{ V}$ to $V_{CC} + 0.5 \text{ V}$	-	±35	mA
I <sub>CC</sub>	supply current		-	+70	mA
I <sub>GND</sub>	ground current		-	<del>-7</del> 0	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation				
	DIP16 package		<u>[1]</u> _	750	mW
	SO16 package		[2] -	500	mW
	SSOP16 package		<u>[3]</u> _	500	mW
	TSSOP16 package		<u>[3]</u> _	500	mW

<sup>[1]</sup> For DIP16 packages: above 70 °C, Ptot derates linearly with 12 mW/K.

## 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Type 74HC2	57					
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	V
Δt/ΔV	input transition rise and fall rates	$V_{CC} = 2.0 \text{ V}$	-	-	625	ns
		V <sub>CC</sub> = 4.5 V	-	1.67	139	ns
		V <sub>CC</sub> = 6.0 V	-	-	83	ns
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
Type 74HCT	257					
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	V
Δt/ΔV	input transition rise and fall rates	$V_{CC} = 4.5 \text{ V}$	-	1.67	139	ns
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C

<sup>[2]</sup> For SO16 packages: above 70 °C, Ptot derates linearly with 8 mW/K.

<sup>[3]</sup> For SSOP16 and TSSOP16 packages: above 60 °C, Ptot derates linearly with 5.5 mW/K.

## 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Uni
			Min	Тур	Max	Min	Max	Min	Max	
74HC25	7									
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A$ ; $V_{CC} = 6.0 \text{ V}$	5.9	6.0	-	5.9	-	5.9	-	٧
		$I_O = -6.0 \text{ mA}$ ; $V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	٧
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 20 \mu A; V_{CC} = 6.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	٧
		$I_O = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	٧
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	±1.0	±1.0	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.5	-	±5.0	±10.0	±10.0	μА
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	160	160	μΑ
Ci	input capacitance		-	3.5	-					рF
74HCT2	57									
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	8.0	-	8.0	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -6 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	٧
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$				-	0.1	-	0.1	
	output voltage	I <sub>O</sub> = 20 μA	-	0	0.1	-	0.33	-	0.4	٧
		$I_{O} = 6.0 \text{ mA}$	-	0.15	0.26	-	±1.0	-	±1.0	٧
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±5.0	-	±10	μΑ
4HC_HCT257_	5							© NXP B.V.	2010. All righ	nts rese

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Table 6. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C			–40 °C to +85 °C		–40 °C to +125 °C	
			Min	Тур	Max	Min	Max	Min	Max	
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at $V_{CC}$ or GND; $I_O = 0$ A	-	-	±0.5	-	80	-	160	μА
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0					μΑ
Δl <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 2.1 \text{ V};$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$								
		per input pin; nI0, nI1 inputs	-	40	144	-	180	-	196	μΑ
		per input pin; OE input	-	135	486	-	608	-	662	μΑ
		per input pin; S input	-	70	252	-	315	-	343	μΑ
Cı	input capacitance		-	3.5	-					pF

# 10. Dynamic characteristics

**Dynamic characteristics** 

**Product data sheet** 

Voltages are referenced to GND (ground = 0 V); For test circuit see Figure 8.

Symbol	Parameter	rameter Conditions		25	°C	–40 °C to +85 °C	-40 °C to +125 °C	Unit
				Тур	Max	Max	Max	
74HC257	7							
t <sub>pd</sub>	propagation delay	nl0 to nY or nl1 to nY; see <u>Figure 6</u>	[1]					
		V <sub>CC</sub> = 2.0 V		36	110	140	165	ns
		V <sub>CC</sub> = 4.5 V		13	22	28	33	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		11	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		10	19	24	28	ns
		S to nY; see Figure 6						
		$V_{CC} = 2.0 \text{ V}$		47	150	190	225	ns
		$V_{CC} = 4.5 \text{ V}$		17	30	38	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		14	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		14	26	33	38	ns
t <sub>en</sub>	enable time	OE to nY; see Figure 7	[2]					
		$V_{CC} = 2.0 \text{ V}$		33	150	190	225	ns
		$V_{CC} = 4.5 \text{ V}$		12	30	38	45	ns
		$V_{CC} = 6.0 \text{ V}$		10	26	33	38	ns
t <sub>dis</sub>	disable time	OE to nY; see Figure 7	<u>[3]</u>					
		$V_{CC} = 2.0 \text{ V}$		41	150	190	225	ns
		V <sub>CC</sub> = 4.5 V		15	30	38	45	ns
		$V_{CC} = 6.0 \text{ V}$		12	26	33	38	ns

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); For test circuit see Figure 8.

Symbol	Parameter	Conditions		25	°C	–40 °C to +85 °C	-40 °C to +125 °C	Unit
				Тур	Max	Max	Max	
t <sub>t</sub>	transition time	see Figure 6	<u>[4]</u>					
		V <sub>CC</sub> = 2.0 V		14	60	75	90	ns
		V <sub>CC</sub> = 4.5 V		5	12	15	18	ns
		V <sub>CC</sub> = 6.0 V		4	10	13	15	ns
$C_{PD}$	power dissipation capacitance	per multiplexer; V <sub>I</sub> = GND to V <sub>CC</sub>	<u>[5]</u>	45	-			pF
74HCT2	57							
t <sub>pd</sub>	propagation delay	nl0 to nY or nl1 to nY; see Figure 6	[1]					
		V <sub>CC</sub> = 4.5 V		16	30	38	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		13	-	-		ns
		S to nY; see Figure 6						
		V <sub>CC</sub> = 4.5 V		20	35	44	53	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		17	-			ns
t <sub>en</sub>	enable time	$\overline{\text{OE}}$ to nY; V <sub>CC</sub> = 4.5 V; see Figure 7	<u>[2]</u>	15	30	38	45	ns
t <sub>dis</sub>	disable time	$\overline{\text{OE}}$ to nY; $V_{\text{CC}} = 4.5 \text{ V}$ ; see Figure 7	<u>[3]</u>	16	30	38	45	ns
t <sub>t</sub>	transition time	V <sub>CC</sub> = 4.5 V; see Figure 6	<u>[4]</u>	5	12	15	18	ns
$C_{PD}$	power dissipation capacitance	per multiplexer; V <sub>I</sub> = GND to V <sub>CC</sub>	<u>[5]</u>	45	-			pF

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PHL}$ ,  $t_{PLH}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

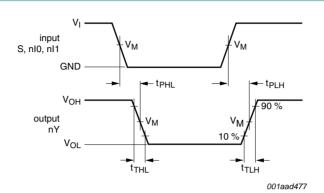
 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

<sup>[2]</sup>  $t_{en}$  is the same as  $t_{PZH}$ ,  $t_{PZL}$ .

<sup>[3]</sup>  $t_{dis}$  is the same as  $t_{PHZ}$ ,  $t_{PLZ}$ .

<sup>[4]</sup>  $t_t$  is the same as  $t_{THL}$ ,  $t_{TLH}$ .

### 11. Waveforms



Measurement points are given in Table 8.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Fig 6. Propagation delays input (S, nI0, nI1) to output (nY) and output (nY) transition times

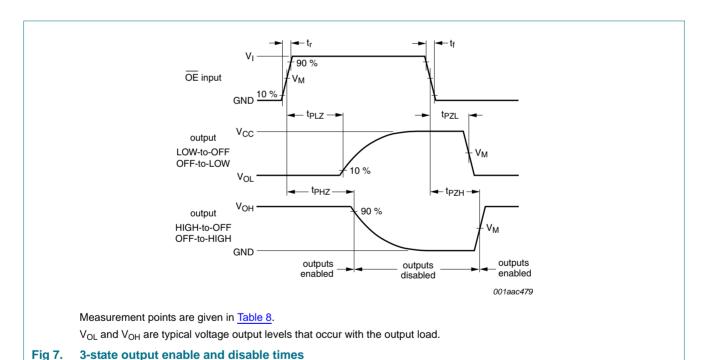
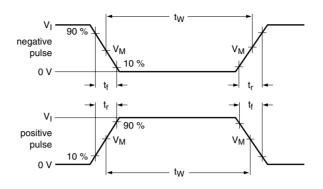
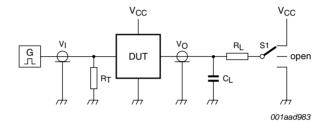


Table 8. Measurement points

Туре	Input	Output	
	V <sub>M</sub>	V <sub>M</sub>	
74HC257	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	
74HCT257	1.3 V	1.3 V	





Measurement points are given in Table 8 and test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_L$  = Load resistor.

Fig 8. Test circuit for switching times

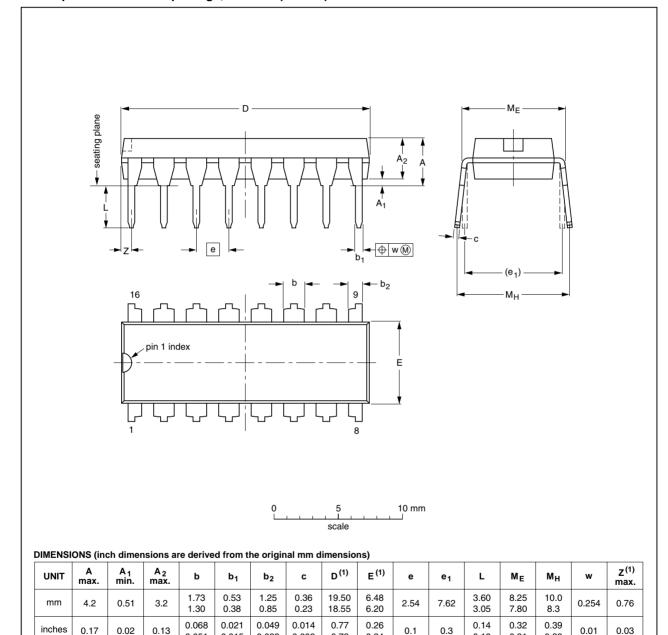
Table 9. Test data

Туре	Input	Input		Input Load		Switch posi	Switch position		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>		
74HC257	$V_{CC}$	6 ns	50 pF	1 kΩ	open	GND	V <sub>CC</sub>		
74HCT257	3 V	6 ns	50 pF	1 kΩ	open	GND	V <sub>CC</sub>		

## 12. Package outline

#### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.015

0.033

0.009

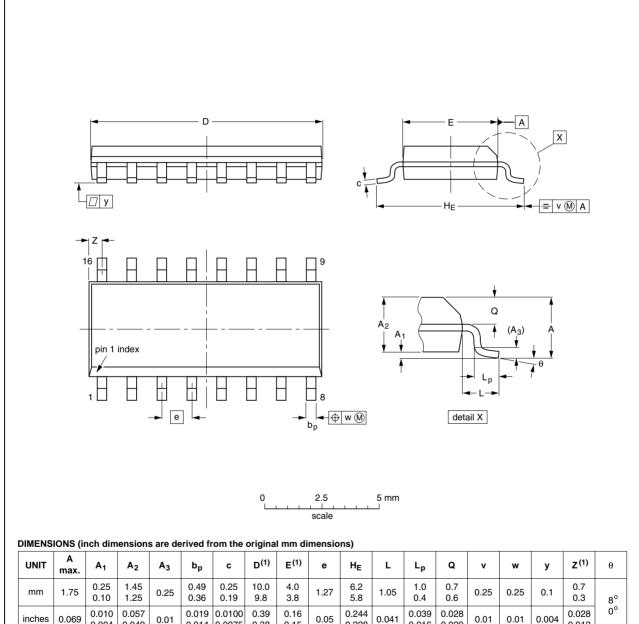
0.051

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE
SOT38-4					<del>95-01-14</del> 03-02-13

Fig 9. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



ι	JNIT	A max.	<b>A</b> <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
	mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
in	ches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

#### Note

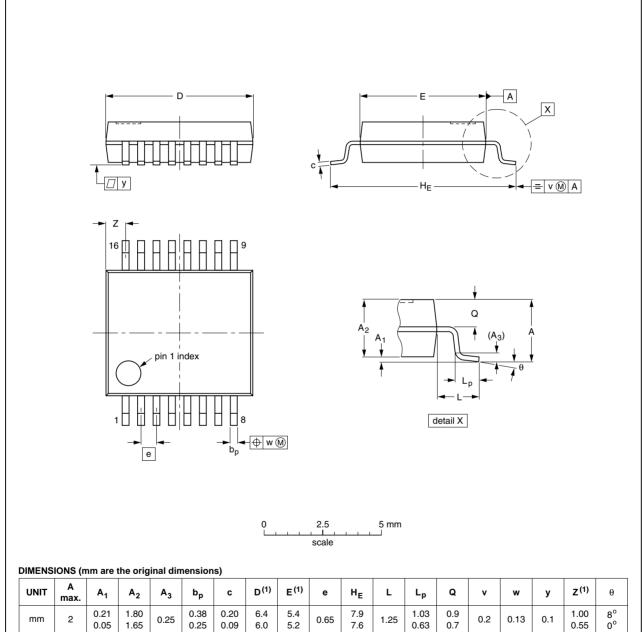
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

Fig 10. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

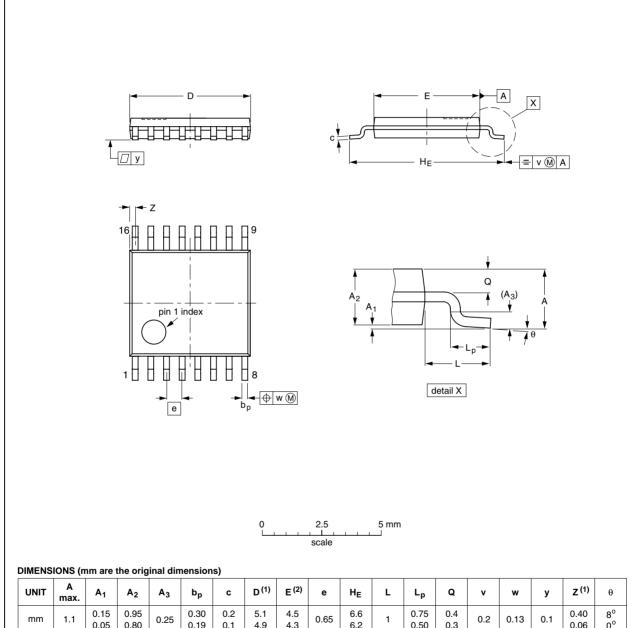
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT338-1		MO-150				<del>99-12-27</del> 03-02-19	

Fig 11. Package outline SOT338-1 (SSOP16)

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE			
,	VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
	SOT403-1		MO-153				<del>-99-12-27</del> 03-02-18	

Fig 12. Package outline SOT403-1 (TSSOP16)

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## 13. Revision history

#### Table 10. Revision history

**Product data sheet** 

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT257_5	20100113	Product data sheet	-	74HC_HCT257_4
Modifications:	• Table 7 "Dy	namic characteristics": cha	anged 30E to 0E	
74HC_HCT257_4	20090608	Product data sheet	-	74HC_HCT257_3
74HC_HCT257_3	20050920	Product data sheet	-	74HC_HCT257_CNV_2
74HC_HCT257_CNV_2	19980930	Product specification	-	-

## 14. Legal information

#### 14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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